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# 2SC4500(L)/(S)

Silicon NPN Epitaxial

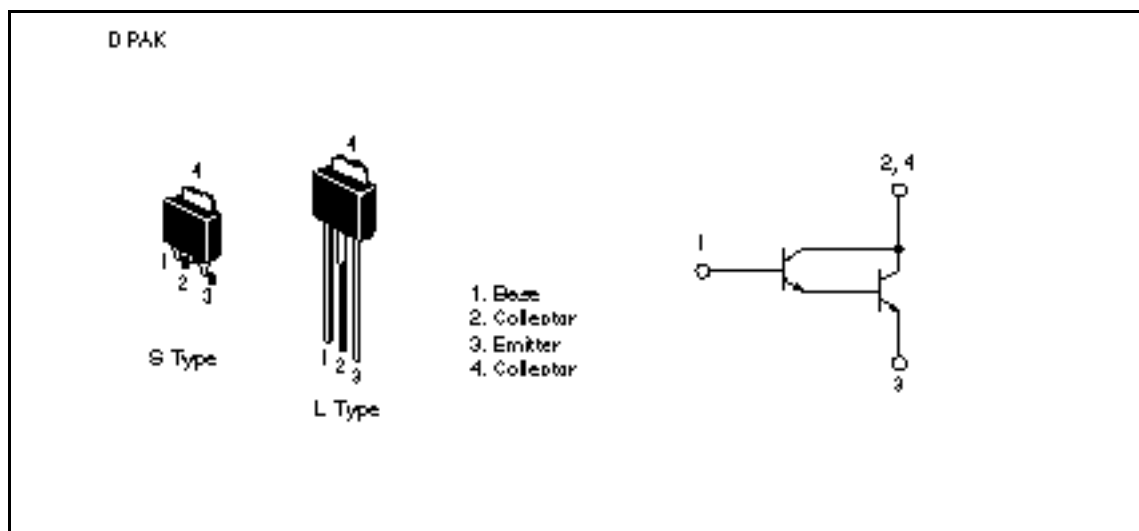
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## Application

Low frequency amplifier

## Outline



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### Absolute Maximum Ratings (Ta = 25°C)

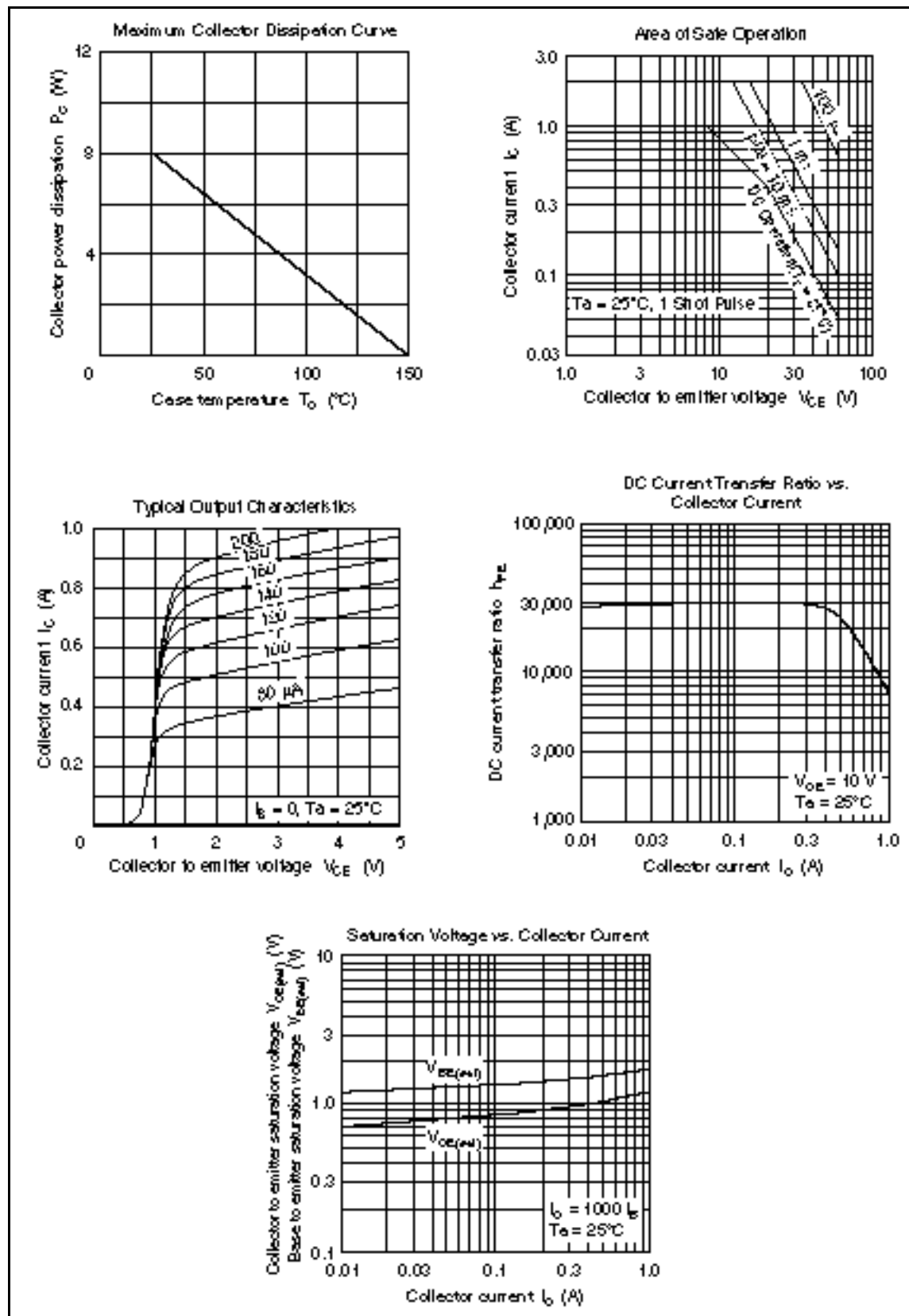
| Item                         | Symbol        | Ratings     | Unit |
|------------------------------|---------------|-------------|------|
| Collector to base voltage    | $V_{CBO}$     | 60          | V    |
| Collector to emitter voltage | $V_{CEO}$     | 60          | V    |
| Emitter to base voltage      | $V_{EBO}$     | 7           | V    |
| Collector current            | $I_C$         | 1           | A    |
| Collector peak current       | $I_{C(peak)}$ | 2           | A    |
| Collector power dissipation  | $P_C$         | 0.8         | W    |
|                              | $P_C^{*1}$    | 8           |      |
| Junction temperature         | $T_j$         | 150         | °C   |
| Storage temperature          | $T_{stg}$     | –55 to +150 | °C   |

Note: 1. Value at  $T_C = 25^\circ\text{C}$ .

### Electrical Characteristics (Ta = 25°C)

| Item                                    | Symbol        | Min  | Typ | Max | Unit          | Test Conditions                                                                      |
|-----------------------------------------|---------------|------|-----|-----|---------------|--------------------------------------------------------------------------------------|
| Collector to emitter breakdown voltage  | $V_{(BR)CEO}$ | 60   | —   | —   | V             | $I_C = 1\text{ mA}$ , $R_{BE} = \bullet$                                             |
| Emitter to base breakdown voltage       | $V_{(BR)EBO}$ | 7    | —   | —   | V             | $I_E = 0.1\text{ mA}$ , $I_C = 0$                                                    |
| Collector cutoff current                | $I_{CBO}$     | —    | —   | 10  | $\mu\text{A}$ | $V_{CB} = 60\text{ V}$ , $I_E = 0$                                                   |
| DC current transfer ratio               | $h_{FE}$      | 2000 | —   | —   |               | $V_{CE} = 10\text{ V}$ , $I_C = 500\text{ mA}^{*1}$                                  |
| Collector to emitter saturation voltage | $V_{CE(sat)}$ | —    | —   | 1.5 | V             | $I_C = 500\text{ mA}$ , $I_B = 0.5\text{ mA}^{*1}$                                   |
| Base to emitter saturation voltage      | $V_{BE(sat)}$ | —    | —   | 2.0 | V             | $I_C = 500\text{ mA}$ , $I_B = 0.5\text{ mA}^{*1}$                                   |
| Turn on time                            | $t_{on}$      | —    | 100 | —   | ns            | $V_{CC} = 12\text{ V}$ , $I_C = 250\text{ mA}$ ,<br>$I_{B1} = -I_{B2} = 5\text{ mA}$ |
| Turn off time                           | $t_{off}$     | —    | 600 | —   | ns            |                                                                                      |

Note: 1. Pulse Test.



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### Hitachi, Ltd.

Semiconductor & IC Div.

Nippon Bldg., 2-6-2, Ohite-machi, Chiyoda-ku, Tokyo 100, Japan

Tel Tokyo (03) 3270-2111

Fax (03) 3270-5109

For further information write to:

Hitachi America, Ltd.

Semiconductor & IC Div.

2000 Sierra Point Parkway

Brea, CA 94005-4835

U.S.A.

Tel 415-589-8300

Fax 415-583-4207

Hitachi Europe GmbH

Electronic Components Group

Continental Europe

Dannewitzstrasse 3

D-85622 Feldkirchen

München

Tel 089-9 94 80-0

Fax 089-9 29 30 00

Hitachi Europe Ltd.

Electronic Components Div.

Northern Europe Headquarters

Whitebrook Park

Lower Cookham Road

High Wycombe

Berkshire SL6 8YA

United Kingdom

Tel 0628-885000

Fax 0628-778322

Hitachi Asia Pte. Ltd.

45 Collyer Quay #20-00

Hitachi Tower

Singapore 0404

Tel 535-2100

Fax 535-1533

Hitachi Asia (Hong Kong) Ltd.

Unit 705, North Tower,

World Finance Centre

Harbour City, Canton Road

Tsim Sha Tsui, Kowloon

Hong Kong

Tel 27359218

Fax 27308074

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